

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
		Yokoo.K.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/24 18:21
		S46 and (TFT	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/24 18:13
		S46 and (TFT or "thin film transistor" or "thin-film transistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/24 18:13
		S46 and (TFT or "thin film transistor" or "thin-film transistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/24 18:13
		S10 and (TFT or "thin film transistor" or "thin-film transistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/24 18:13
S1	14	US-6140167-\$.DID. OR US-5710478-\$.DID. OR US-6329258-\$.DID. OR US-5519244-\$.DID. OR US-4980303-\$.DID. OR US-4912053-\$.DID. OR US-5143820-\$.DID.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/20 11:55
S2	15	("5138237" "5212426" "5341063" "5430348" "5550435").PN. OR ("5710478").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/01/20 12:15
S3	8	("4988638" "5210472" "5229331" "5372973" "5482870" "5710478" "6020683" "6057555").PN. OR ("6344378").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/01/20 12:16
S4	9	("4988638" "5210472" "5229331" "5372973" "5482870" "5710478" "6020683" "6057555" "6249327").PN. OR ("6504170").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/01/20 12:17

S5	65	("3500102" "3814968" "3883760" "3970887" "4575765" "4859304" "4874981" "4940916" "4992137" "5000208" "5024722" "5049520" "5100355" "5141461" "5151061" "5162704" "5186670" "5191217" "5199917" "5204581" "5205770" "5210472" "5212426" "5219310" "5229331" "5229682" "5232549" "5259799" "5283500" "5329207" "5342477" "5358599" "5358601" "5358908" "5372973" "5374868" "5391259" "5448133" "5451830" "5483118" "5500750" "5620832" "5621272" "5632664" "5633560" "5637023" "5643033" "5643817" "5648698" "5648699").PN. OR ("6020683").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/01/20 12:18
S6	196	("2959704" "3419746" "3466485" "3665241" "3748523" "3805126" "3814968" "3852595").PN. OR ("3970887"). URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/01/20 12:19
S7	39	lee-ji-ung.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/20 12:24
S8	79	lee-john.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/20 12:24
S9	18	moradi-benham.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/20 12:24
S10	2454	(313/310,336).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/20 12:57

S11	59	S10 and (TFT or "thin film transistor" or "thin-film transistor")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/20 13:17
S12	42	S11 and (FED or "field emitter")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/20 13:16
S13	6	("6137219").URPN.	USPAT	OR	ON	2006/01/20 13:02
S14	11	("5012153" "5210472" "5359256" "5698942" "5907215").PN. OR ("6137219").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/01/20 13:02
S15	726	S10 and (FED or "field emitter")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/20 13:04
S16	27	S15 and (emitter with drain)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/20 13:17
S17	19	S15 and (emitter near5 drain)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/20 13:04
S18	6	("4891093" "5268648" "5359256" "5479256" "5688707").PN. OR ("6020595").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/01/20 13:05
S19	11	("5266530" "5455196" "5532177").PN. OR ("5688707").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/01/20 13:06
S20	12	("3755704" "4513308" "4766340" "4908539" "5173634" "5448133" "5550435" "5965972").PN. OR ("6163107").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/01/20 13:06
S21	0	257/10,49-75	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/20 13:16

S22	9078	(257/10,49-75).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/20 13:16
S23	461	S22 and (FED or "field emitter")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/20 13:20
S24	210	S23 and (TFT or "thin film transistor" or "thin-film transistor")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/20 13:20
S25	4	S24 and (emitter with drain)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/20 13:19
S26	3384	(438/20,149,151,155,180).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/20 13:18
S27	353	S26 and (FED or "field emitter")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/20 13:19
S28	128	S27 and (TFT or "thin film transistor" or "thin-film transistor")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/20 13:19
S29	7	S28 and (emitter with drain)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/20 13:21

S30	103475	((("315") or ("445")).CLAS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/20 13:20
S31	11881	S30 and (FED or "field emitter")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/20 15:01
S32	282	S31 and (TFT or "thin film transistor" or "thin-film transistor")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/20 13:21
S33	8	S32 and (emitter with drain)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/20 13:21
S34	408513	((("257") or ("438")).CLAS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/20 13:21
S35	15527	S34 and (FED or "field emitter")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/20 14:59
S36	1182	S35 and (TFT or "thin film transistor" or "thin-film transistor")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/20 15:00
S37	26	S36 and (emitter with drain)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/20 13:21

S38	408513	((("257") or ("438")).CLAS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/20 15:00
S39	1390	S38 and ((field or electron) adj emitter)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/20 15:00
S40	141	S39 and (TFT or "thin film transistor" or "thin-film transistor")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/20 15:01
S41	134	S39 and ("thin film transistor" or "thin-film transistor")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/20 15:00
S42	103475	((("315") or ("445")).CLAS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/20 15:01
S43	1772	S42 and ((electron or field) adj emitter)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/20 15:01
S44	64	S43 and (TFT or "thin film transistor" or "thin-film transistor")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/20 15:01
S45	20	US-5482870-\$.DID. OR US-5372973-\$.DID. OR US-5229331-\$.DID. OR US-5210472-\$.DID. OR US-4988638-\$.DID. OR US-6057555-\$.DID. OR US-5710478-\$.DID. OR US-6020683-\$.DID. OR US-6249327-\$.DID.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/24 17:33

S46	772	((438/20) or (257/20)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/24 18:25
S47	772	S46	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/24 18:15
S48	29	S47 and TFT	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/24 18:14
S49	225	S47 and (thin adj film or thin\$1film)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/24 18:15
S50	36	S47 and ((thin adj film or thin\$1film) near3 transistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/24 18:26
S51	503	Yokoo-K\$.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/24 18:22
S52	82	Hashiguchi-G\$.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/24 18:24
S53	3	S52 and (thin\$1film or thin adj film)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/24 18:24

S54	1141	((438/20) or (257/10,20)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/24 18:26
S55	702	S54 and (emitter or emission)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/24 18:27
S56	28	S55 and ((thin adj film or thin\$1film) near3 transistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/24 18:27
S57	3797	(313/309-310,336,351).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/24 18:27
S58	2140	S57 and (emitter or emission)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/24 18:27
S59	67	S58 and ((thin adj film or thin\$1film) near3 transistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/24 18:45
S60	5014	(257/66,67,72,57,59).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/24 18:33
S61	2809	(438/149,151,155).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/24 18:33

S62	7442	S60 or S61	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/24 18:33
S63	140	S62 and (field adj emitter or field adj emission)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/24 18:45
S64	17978	("445").CLAS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/24 18:45
S65	285	S64 and ((thin adj film or thin\$1film) near3 transistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/24 18:45
S66	60	S65 and (field adj emitter or field adj emission)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/24 18:45

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